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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT		•		•			
Reverse voltage		V _R	6	V			
DC forward current		I _F	60	mA			
Surge forward current	t _P ≤ 10 ms	I _{FSM}	2.5	A			
Power dissipation		P _{diss}	100	mW			
OUTPUT							
Collector emitter voltage		V _{CEO}	70	V			
Emitter collector voltage		V _{ECO}	7	V			
Collector current		Ι _C	50	mA			
	t _P ≤ 10 ms	Ι _C	100	mA			
Total power dissipation		P _{diss}	150	mW			
COUPLER							
Isolation test voltage between emitter and detector		V _{ISO}	5300	V _{RMS}			
Creepage distance			≥7	mm			
Clearance distance			≥7	mm			
Isolation thickness between emitter and detector Comparative tracking index per DIN IEC 112/VDE 0303, part 1		СТІ	≥ 175				
Isolation resistance	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 25 ^{\circ}\text{C}$	R _{IO}	≥ 10 ¹²	Ω			
Isolation resistance	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 100 ^{\circ}\text{C}$	R _{IO}	≥ 10 ¹¹	Ω			
Storage temperature range		T _{stg}	- 55 to + 150	°C			
Ambient temperature range		T _{amb}	- 55 to + 100	°C			
Soldering temperature ⁽¹⁾	max. 10 s, dip soldering distance to seating plane ≥ 1.5 mm	T _{sld}	260	°C			

Notes

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

(1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
INPUT								
Forward voltage	I _F = 60 mA		V _F		1.25	1.65	V	
Reverse current	V _R = 6 V		I _R		0.01	10	μA	
Capacitance	$V_R = 0 V$, f = 1 MHz		C _O		13		pF	
Thermal resistance			R _{thja}		750		K/W	
OUTPUT								
Collector emitter capacitance	$V_{CE} = 5 V$, f = 1 MHz		C _{CE}		5.2		pF	
Thermal resistance			R _{thja}		500		K/W	
Collector emitter saturation voltage	l _F = 10 mA, l _C = 2.5 mA		V _{CEsat}		0.25	0.4	V	
Coupling capacitance			C _C		0.4		pF	
COUPLER								
Collector emitter leakage current		SFH615AA	I _{CEO}		10	100	nA	
		SFH615AGB	I _{CEO}		10	100	nA	
		SFH615AGR	I _{CEO}		10	100	nA	
	V _{CEO} = 10 V	SFH615ABM	I _{CEO}		10	100	nA	
		SFH615ABL	I _{CEO}		10	100	nA	
		SFH615AY	I _{CEO}		10	100	nA	
		SFH615AB	I _{CEO}		10	100	nA	

Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

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CURRENT TRANSFER RATIO							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I _C /I _F	I _F = 5 mA, V _{CE} = 5 V	SFH615AA	CTR	50		600	%
		SFH615AGB	CTR	100		600	%
		SFH615AGR	CTR	100		300	%
		SFH615ABM	CTR	200		400	%
		SFH615ABL	CTR	200		600	%
		SFH615AY	CTR	50		150	%
		SFH615AB	CTR	80		260	%

SWITCHING CHARACTERISTICS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Turn-on time	I _F = 5 mA	t _{on}		2		μs	
Turn-off time	I _F = 5 mA	t _{off}		25		μs	

TYPICAL CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)



isfh615aa_01





Fig. 2 - Current Transfer Ratio (Typ.) vs. Temperature



Fig. 3 - Transistor Capacitance (Typ.) vs. Collector Emitter Voltage





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Fig. 5 - Output Characteristics (typ.) Collector Current vs. Collector Emitter Voltage



Fig. 6 - Permissible Pulse Handling Capability Forward Current vs. Pulse Width



Fig. 7 - Diode Forward Voltage (typ.) vs. Forward Current



Fig. 8 - Permissible Power Dissipation vs. Temperature

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PACKAGE DIMENSIONS in inches (millimeters)



i178027



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